arXiv:1702.06687v1 [cond-mat.mes-hall] 22 Feb 2017

Origin of luminescence quenching in structures containing CdSe/ZnSe quantum dots with a few Mn^{2+} ions

K. Oreszczuk,* M. Goryca, W. Pacuski, T. Smoleński, M. Nawrocki, and P. Kossacki
Institute of Experimental Physics, Faculty of Physics,
University of Warsaw, ul. Pasteura 5, PL-02-093 Warszawa, Poland

We present a detailed spectroscopic study of the photoluminescence quenching in an epitaxial sample containing CdSe/ZnSe quantum dots (QDs) doped with low concentration of Mn^{2+} ions. Our time-resolved and time-integrated experiments reveal the origin of the quenching observed in macro-photoluminescence studies of ensembles of such dots. We show that incorporation of even a few ions to an individual dot has little influence on its luminescence. At the same time, the presence of Mn^{2+} ions in the sample significantly affects the luminescence intensity of the wetting layer. However, it does not affect the luminescence decay, which suggests that the observed quenching occurs for excited excitonic states.

PACS numbers: 75.50.Pp, 78.67.Hc, 78.66.Hf, 78.55.-m, 78.20.Ls

I. INTRODUCTION

Thanks to exchange interaction between magnetic ions and band carriers, Diluted Magnetic Semiconductors (DMS) exhibit giant Zeeman effect and related extraordinary magneto-optical properties[1]. Influence of magnetic ions can be further enhanced by introducing them to low dimensional semiconductor structures,[2–8] which could be applied in the field of spintronics,[9] solotronics[10,11] and in the photophysics[12]. From this point of view, particularly interesting are structures constructed of Mn-doped wide-gap II-VI semiconductors such as ZnSe, ZnS or ZnO. This is because excitons in wide gap semiconductors exhibit high binding energy and high oscillator strength which open possibility of working at room temperature, and which result in high efficiency of photon sources and in strong coupling with photonic modes.[13–15] However, the addition of Mn^{2+} ions to both bulk material and to the low dimensional structures results in that case in suppression of excitonic luminescence[16–19]. This is due to the opening of a new, sensitive to magnetic field channels of nonradiative relaxation of excitons[12,20–26]. Therefore, of great interest were the results obtained on recently grown individual self-organized CdSe/ZnSe QDs containing single Mn^{2+} ions indicating that in such structures a suppression of the luminescence does not occur effectively, while the specific magneto-optical properties of DMS are preserved[11,27,28].

Explanation of the absence of luminescence quenching in a QD with a single magnetic ion may have a double importance. On the one hand to understand the physics which lies behind it, on the other it may indicate how to reduce luminescence quenching in structures with a higher content of Mn^{2+}, which from the point of view of their magneto-optical properties would be highly desirable. For this purpose in the present study we investigate the change in luminescence quenching when the number of Mn^{2+} ions in the individual CdSe/ZnSe QDs is increased from one to several of them.

II. SAMPLE AND EXPERIMENTAL SETUP

The samples used in this study were grown using molecular beam epitaxy (MBE) technique. They contain self-assembled CdSe QDs between two ZnSe layers (barriers) on GaAs substrate. In some samples during the growth process, the Mn^{2+} ions were introduced simultaneously with CdSe layer. As the QDs with a few magnetic ions were the subject of our studies, the concentration of dopants was a few times larger than concentration optimised for analogous QDs with single magnetic ions[7,11,29–35]and two magnetic ions[36,37], but smaller than for QDs with many of them[38–40].

The identification of the QDs with various number of magnetic ions and further measurements were performed at temperature equal to 6 K in liquid helium cooled cryostat with superconducting magnet which produced magnetic field up to 10 T. Photoluminescence (PL) measurements were performed with the use of continous wave (CW) lasers with wavelengths equal to 488 nm and 405 nm. For micro-photoluminescence (μ-PL) measurements the sample was attached directly to immersion reflection microscope. In this configuration the size of laser spot on the sample was below 1 μm. The luminescence from the sample was spectrally resolved by a monochromator equipped with a CCD camera. For time-resolved measurements a 425 nm pulsed laser and a streak camera were used.

III. PHOTOLUMINESCENCE QUENCHING - ENSEMBLE MEASUREMENTS

In order to verify the presence of the PL quenching in our Mn-doped sample we performed macro-PL measurements of QDs ensemble also in the reference sample without Mn dopants. As shown in Fig. 1, in the case of Mn-doped sample a significant rise of the PL intensity in σ^+ circular polarization of detection is observed. The effect is less pronounced for high excitation power. Such

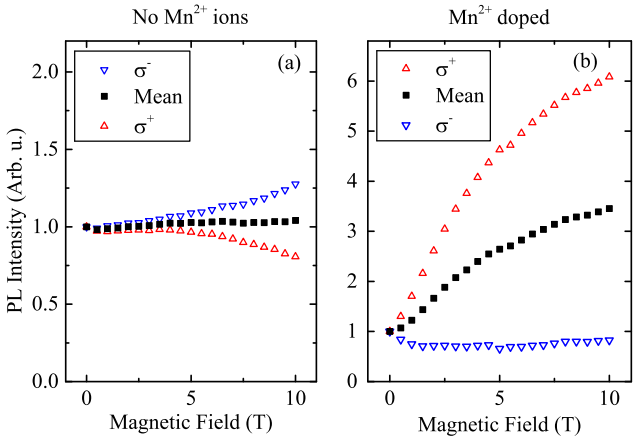

FIG. 1: Dependence of integrated PL intensity of an ensemble of QDs measured in σ^+ polarization of detection as a function of magnetic field for (a) the sample without Mn ions and (b) the Mn-doped sample. In the latter case significant rise of the PL intensity with magnetic field is observed, which is typical for magnetic ion-related PL quenching. Please note, that the scales on vertical axes are different.

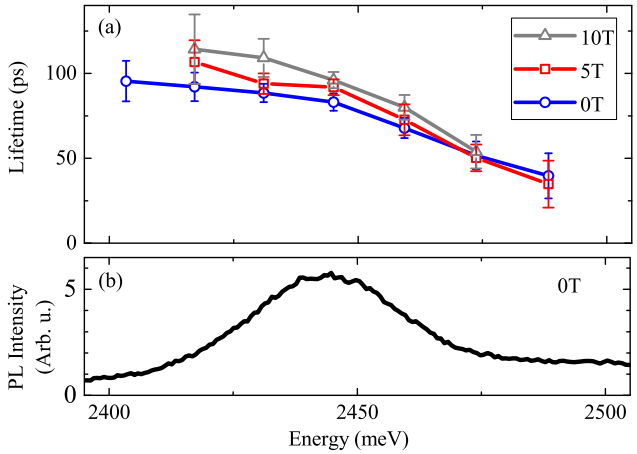

FIG. 2: (a) Lifetime of the ensemble luminescence of the Mn^{2+} doped QDs in various magnetic fields as a function of photon energy. (b) Time-integrated luminescence spectrum of QDs as excited by 444 nm pulsed laser in temperature 1.8 K.

behavior is a well-known fingerprint of magnetic ions-related PL quenching[20,23,24,41,42] due to non-radiantive exciton recombination channel corresponding to excitation of the Mn ions. The total spin S of the ion is equal to $\frac{3}{2}$ for excited $^4T_1$ and $^4T_2$ states and $\frac{5}{2}$ for $^6A_1$ ground state. The selection rules for the spin projection forbid excitation from ground states with $S_z = \pm\frac{5}{2}$. Thus, spin orientation in high magnetic fields leads to suppression of the PL qunching. In similar experiment such phenomena is not observed in the case of the sample without Mn^{2+} ions. The only observed PL intensity change is a slight polarization of the whole spectrum due to excitonic spin relaxation[43,44].

To confirm the nature of the observed phenomena in the Mn-doped sample, the measurements of the luminescence lifetime were performed. One could expect the lifetime to rise significantly with magnetic field as the PL quenching recombination channel is turned off, but this is not the case in our sample. Average lifetime is equal to about 100 ps and does not depend significantly on the value of the magnetic field (see Fig. 2). This fact indicates that the observed PL quenching is not related to the non-radiative recombination channels of the relaxed exciton states (the PL is related to), but must occur before the relaxation of photocreated carriers (presumably in the barriers). The decrease of the decay time with increase of the PL energy is probably related to interdot transfer of the excitation[45].

IV. IDENTIFICATION OF SINGLE QDs WITH A FEW Mn^{2+} IONS

In order to investigate in detail the origin of the observed PL quenching we performed micro-PL measurements of single QDs. Due to small laser spot on the sample it was possible to separate well-resolved PL lines originating from single QDs in the low energy tail of the QD ensemble spectrum. Those lines are situated on top of spectrally-broad background, typically ascribed to wetting layer usually present in samples with QDs grown in Stranski – Krastanov growth mode[46]. Among typical sharp lines related to non-magnetic dots we also observe broader features of similar, triangular shape with well visible splitting in the middle (see Fig. 3g-i). The typical width of those features is about 1.2 meV, while the width of the splitting is typically equal to about 0.4 meV. Since such features are not observed in the case of similar samples with no magnetic impurities, we tentatively relate them to QDs containing a few Mn^{2+} ions. Inferring from the width of the features, the Mn^{2+} ions are positioned in such a way that the exciton-Mn exchange interaction has modest strength when compared to the case of previously investigated CdSe QDs with single Mn^{2+} ions[11,28]. In order to support this hypothesis we perform simulations of exciton spectrum in QDs with different number of Mn^{2+} ions. The model used in simulations is based on model of exciton in QDs with single dopant[11] and expanded to describe interactions with many ions. Hamiltonian of the exciton in such a QD is presented in Eq. (1). J_e, J_h, S_k, are the spin operators of electron, hole and kth Mn^{2+} ion spin operators. Light-heavy hole energy difference is denoted by Δ_{l-h}, dark-bright exciton splitting by δ_0 and splitting due to geometric anisotropy of the QD is equal to δ_1. g_e, g_h, g_m are the g-factors of electron, hole and Mn^{2+} ions, respectively. E_0, δ_1, g_e, A_{e_k} were cho-

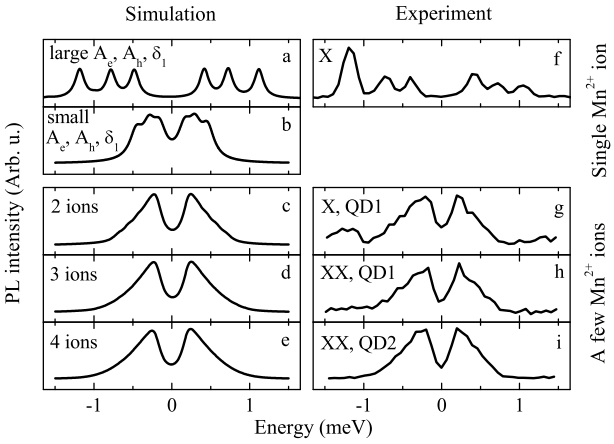

FIG. 3: Left – simulations: (a) Spectrum of QD with single Mn^{2+} ion. (b) QD with single Mn^{2+} ion, low exchange constant for exciton and ion. (c-e) QDs with two, three and four Mn^{2+} ions, respectively. Right – experiment: (f) QD with single Mn^{2+} ion. (g), (h) exciton and biexciton in QD with a few Mn^{2+} ions. (i) biexciton in QD with a few Mn^{2+} ions.

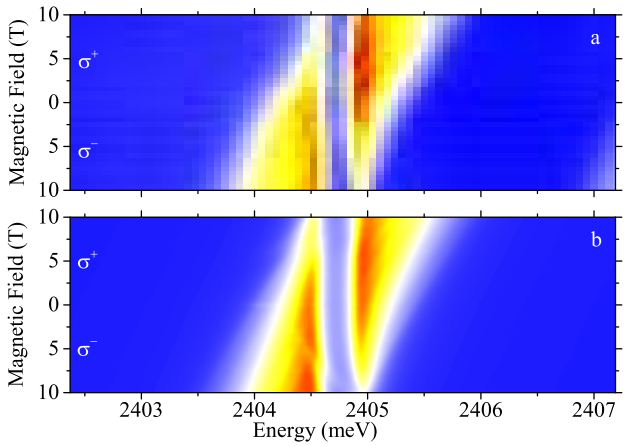

FIG. 4: PL spectrum of QD with a few Mn^{2+} ions plotted as a function of the magnetic field (a) and a corresponding simulation (b).

sen to fit experimental data. Ratios $g_e/g_h = -1.25$ and $A_{e_k}/A_{h_k} = -1/2$ and values of $\delta_0 = 1\,\mathrm{meV}$, $g_m = 2$ and $\Delta_{l-h} = 30\,\mathrm{meV}$ are based on preceding research[11,27].

$$\begin{aligned} H_X =& E_0 + \Delta_{l-h}\frac{1}{2}[(3/2)^2 - (J_h^z)^2] - \delta_0\frac{2}{3}J_e^z J_h^z + \\ &+\delta_1\frac{2}{3}\left[J_e^y\left(J_h^x\right)^3 - J_e^x\left(J_h^y\right)^3\right] + \\ &-\mu_B B(g_e J_e^z + g_h J_h^z) + \\ &+\sum_k(\mu_B B g_m J_k^z + A_{h_k}\vec{J}_h\vec{S}_k + A_{e_k}\vec{J}_e\vec{S}_k) \end{aligned} \tag{1}$$

Results of those simulations are illustrated in Fig. 3, together with experimentally obtained spectra of QDs containing one and – presumably – a few magnetic impurities. Even though we are not able to resolve the multitude of excitonic lines in the case of a few Mn^{2+} ions, it is still possible to analyze general shape of resultant broad feature in the spectrum. For example the splitting always visible in the middle of the feature is related to the anisotropic part of electron-hole exchange interaction (δ_1). Importantly, we can distinguish QDs with exactly one Mn^{2+} ion from those containing more dopants. In the case of a single dopant the broad feature in the spectrum maintains approximately rectangular shape for broad range of QD parameters - anisotropy splitting, g-factors of exciton and ion and exchange constants (see Fig. 3a-b) The identification of the QD with a few Mn^{2+} dopants may be further confirmed by the analysis of the PL spectrum measured in magnetic field. As shown in Fig. 4, the evolution of the QD spectrum with the field is well reproduced with our model.

V. PHOTOLUMINESCENCE QUENCHING IN AN INDIVIDUAL QD

The existence of the quenching of the excitons confined inside QD was verified with the use of two different methods. The first one is based on measuring total intensity of PL lines originating from recombination of excitons confined in the QD for various values of magnetic field applied in the Faraday configuration. The sample was illuminated with a 488 nm CW laser and the intensity of PL lines was determined after subtracting the broad background from the PL spectra. If the effective PL quenching was present in the observed QDs, the PL intensity should significantly increase in magnetic field due to blockade of non-radiative recombination channels[20,23]. In our case we observed no significant variation of the photoluminescence intensity for all magnetic fields up to 10 T and both circular polarizations of detection (see Fig. 5). Such variation was, however, observed for the broad background (see Fig. 6) related to the wetting layer. Similarly to the effect observed in macro-PL , the intensity variation was decreasing with increasing excitation power.

The second method is based on a direct measurement of the PL lifetime. Recombination channel corresponding to intracentric transitions – if such exist – should shorten the lifetime of the excitons confined in the QD. The presence of the PL quenching can be verified either by analysing dependence of luminescence lifetime as a function of magnetic field or by direct comparison of the lifetime of the exciton in a QD without Mn^{2+} ions and in a QD with a few Mn^{2+} ions. We have measured lifetimes of exciton (X) and biexciton (XX) luminescence peaks as a function of magnetic field. Neither of these two peaks show significant dependence on the field. For exemplary QD with a few Mn^{2+} ions the X lifetime is equal to 250 ps $\pm$ 15 ps, while the XX lifetime is 120 ps $\pm$ 7 ps for all

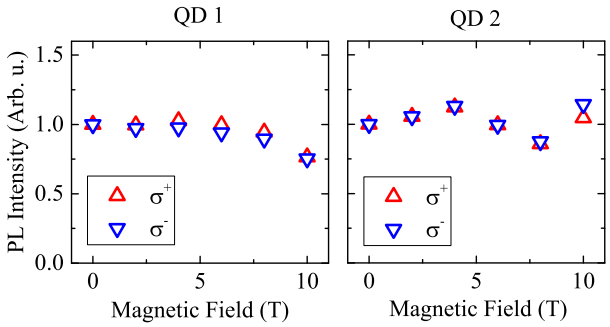

FIG. 5: Dependence of integrated PL intensity of two QDs with a few Mn^{2+} ions. Intensity is measured as a function of magnetic field in both polarizations of detection.

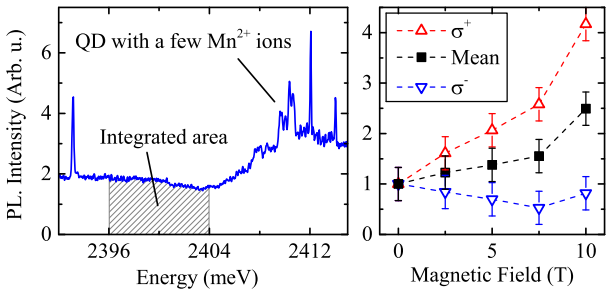

FIG. 6: PL Intensity of the broad background photoluminescence as a function of magnetic field in both circular polarizations of detection.

magnetic fields up to 10 T. Also, the lifetimes of excitonic complexes' PL peaks for all investigated QDs lie in the range expected for QDs without magnetic dopants[11,47].

Similarly, in the case of the broad background no significant effect of the magnetic field on the PL decay was observed. The decay can be described with good accuracy with two-exponential curve (see Fig. 7). The characteristic times were equal to 230 ps ± 30 ps for the longer component and about 30 ps ± 5 ps for the shorter component. Neither long nor short characteristic time reveals any significant dependence on magnetic field and circular polarisation of detection.

All these results show that the PL quenching is not efficient in the case of excitons confined in QDs under investigation. However, it significantly affects the broad PL feature related to the wetting layer. The fact that the lifetime of this feature is not affected by the magnetic field suggests that the non-radiative recombination channels affect mostly higher (excited) excitonic states and not the relaxed states the luminescence come from.

VI. CONCLUSIONS

We have performed a detailed magneto-optical study of the PL quenching in Mn-doped CdSe/ZnSe QDs. Our time-resolved and time-integrated experiments indicate

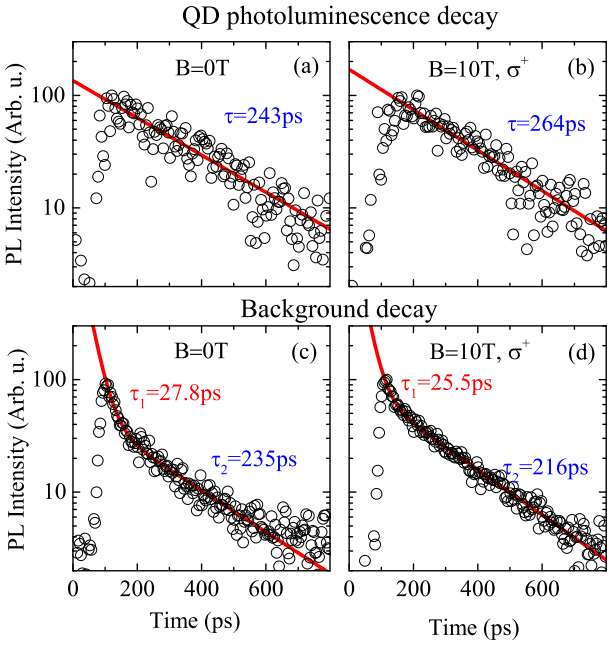

FIG. 7: (a), (b) Photoluminescence intensity decay of neutral exciton line related to an individual QD with a few Mn^{2+} ions, after pulsed excitation in $B = 0$ and $B = 10$ T. (c), (d) Analogous result obtained for the broad luminescence background present in the micro-PL measurements.

the origin of the quenching observed in macro-PL measurements of ensembles of such QDs. All discussed arguments clearly indicate, that the magnetic ions-related quenching does not occur effectively for excitons confined in QDs under our experimental conditions and – if any such quenching exists – it cannot explain effects observed in QD ensembles experiments. However, such quenching is observed for the PL related to the wetting layer. At the same time it does not affect significantly the lifetime of the luminescence. Such observation suggests that the quenching is not related to the non-radiative recombination channels of the relaxed exciton states, but it is caused by depopulation of the excited photocreated carriers.

Acknowledgments

This work was partially supported by the Polish National Science Centre under decision DEC-2013/09/B/ST3/02603, DEC-2015/18/E/ST3/00559, DEC-2011/02/A/ST3/00131, DEC-2012/05/N/ST3/03209. Project was carried out with the use of CePT, CeZaMat, and NLTK infrastructures financed by the European Union - the European Regional Development Fund within the Operational Programme „Innovative economy".

* Electronic address: Kacper.Oreszczuk@fuw.edu.pl

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